### TOSHIBA Photocoupler Photo Relay

### TLP797J

## Telecommunication Measurement Instrumenation FA

The TOSHIBA TLP797J consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a six lead plastic DIP package (DIP6).

The TLP797J is a bi-directional switch can replace mechanical relays in many applications.

- 6 pin DIP (DIP6)
- 1-form-A
- Peak off-state voltage: 600 V (min)
- Trigger LED current: 5 mA (max)
- On-state current: 100 mA (max)
- On-state resistance:  $35 \Omega$  (max)
- Isolation voltage: 5000 Vrms (min)
- UL recognized: UL1577, file No. E67349
- Option(D4) type

VDE approved: DIN EN 60747-5-2

Certificate No. 40009302

Maximum operating insulation voltage: 890 Vpk

Maximum permissible over voltage: 6000 Vpk

Note: When ordering an EN60747-5-2 approved device,

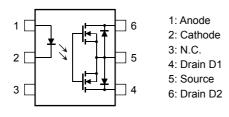
"Option (D4)" should be designated.

#### Construction mechanical rating

	7.62 mm pitch 10.16 mm pitch standard type TLPXXXF type	
Creepage distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation thickness	0.4 mm (min)	0.4 mm (min)

Note: When applying safety standard certification, use the standard part number, e.g., TLP797J.

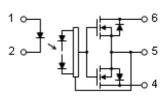
### Pin Configurations (top view)



# 

Weight: 0.4 g (typ.)

### **Schematic**



### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Forward current		l <sub>F</sub>	50	mA	
LED Pea (10)	Forward current derating (Ta ≥ 25°C)		ΔI <sub>F</sub> /°C	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)		I <sub>FP</sub>	1	А
	Reverse voltage		$V_{R}$	5	V
	Junction temperature		Tj	125	°C
	Off-state output ter	ff-state output terminal voltage		600	V
Detector ·		A connection	I <sub>ON</sub>	100	mA
	On-state current	B connection		100	
		C connection		200	
	On-state current derating (Ta ≥ 25°C)	A connection	Δl <sub>ON</sub> /°C	-1.0	mA/°C
		B connection		-1.0	
		C connection		-2.0	
	Junction temperature		Tj	125	°C
Storage temperature range		T <sub>stg</sub>	-55 to 125	°C	
Operating temperature range		T <sub>opr</sub>	-40 to 85	°C	
Lead soldering temperature (10 s)		T <sub>sol</sub>	260	°C	
Isolation voltage (AC, 1 minute, R.H. ≤ 60%) (Note 1)		BVS	5000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device: Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	$V_{DD}$	_	_	480	V
Forward current	ΙF	7.5	15	25	mA
On-state current	I <sub>ON</sub>	_	_	100	mA
Operating temperature	T <sub>opr</sub>	-20		65	°C

Note:

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